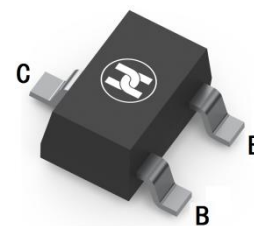


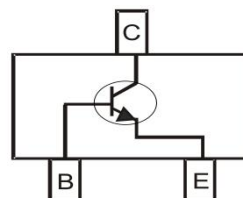
BIPOLAR TRANSISTOR (NPN)

FEATURES

- Radio frequency amplifier
- High transition frequency
- High gain with low collector-to base time constant
- Low noise (NF)



SOT-323



MECHANICAL DATA

- Case: SOT-323
- Case Material: Molded Plastic. UL flammability
- Classification Rating: 94V-0
- Weight: 0.008 grams (approximate)

Maximum Ratings (T_A=25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	20	V
Collector-Emitter Voltage	V _{CEO}	11	V
Emitter-Base Voltage	V _{EBO}	3	V
Collector Current -Continuous	I _C	50	mA
Collector Power Dissipation	P _D	0.2	W
Junction Temperature	T _J	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C

ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit
Collector-base breakdown voltage I _C =10μA, I _E =0	V _{(BR)CBO}	20	-	-	V
Collector-emitter breakdown voltage I _C =1mA, I _B =0	V _{(BR)CEO}	11	-	-	V
Emitter-base breakdown voltage I _E =10μA, I _C =0	V _{(BR)EBO}	3	-	-	V
Collector cut-off current V _{CB} =10V, I _E =0	I _{CBO}	-	-	0.5	μA
Emitter cut-off current V _{EB} =2V, I _C =0	I _{EBO}	-	-	0.5	μA
DC current gain V _{CE} =10V, I _C =5mA	h _{FE}	56	-	270	-
Collector-base saturation voltage I _C =10mA, I _B =5mA	V _{CE(sat)}	-	-	0.5	V
Transition frequency V _{CE} =10V, I _C =10mA, f=500MHz	f _T	-	1.2	-	GHz
Output capacitance V _{CB} =10V, I _E =0, f=1MHz	C _{ob}	-	-	1.5	pF
Collector-base time constant V _{CB} =10V, I _C =10mA, f=31.8MHz	C _C , r _{bb}	-	-	12	pS
Noise figure V _{CE} =6V, I _C =2mA, f=500MHz, R _g =50Ω	NF	-	3.5	-	dB

CLASSIFICATION OF h_{FE}

Rank	N	P	Q
Range	56-120	82-180	120-270

BIPOLAR TRANSISTOR (NPN)

Typical Characteristics

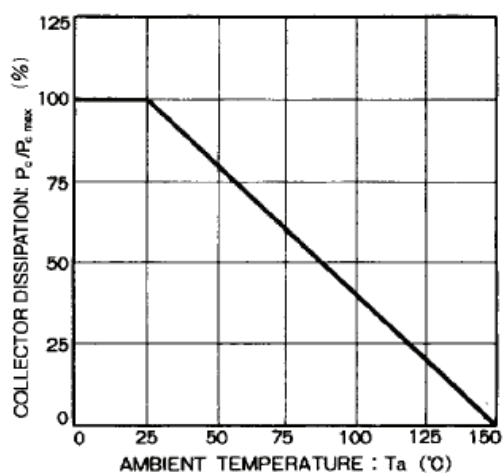


Figure 1

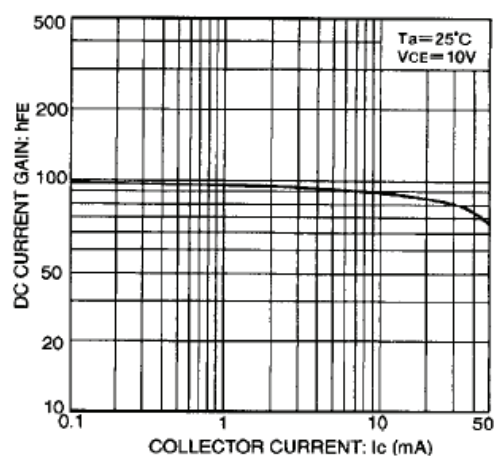


Figure 2

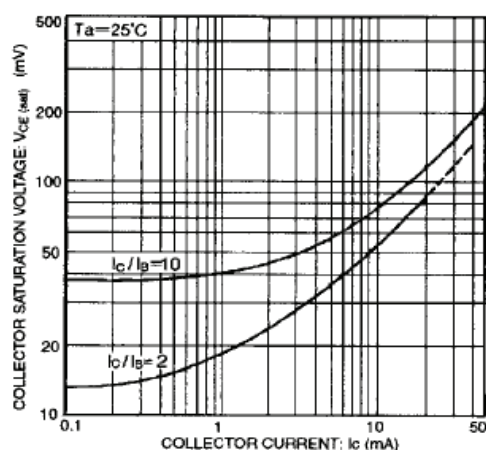


Figure 3

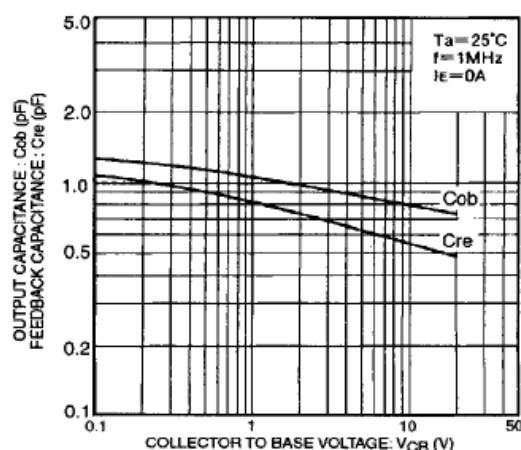


Figure 4

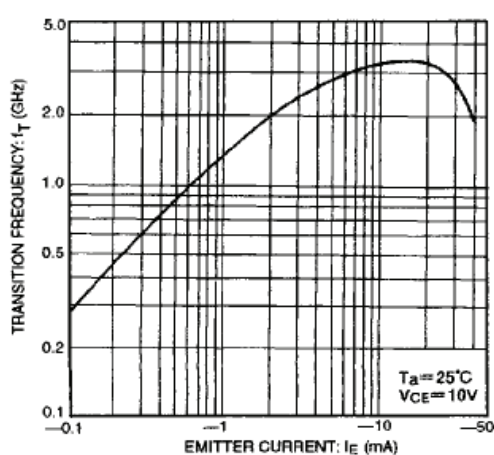


Figure 5

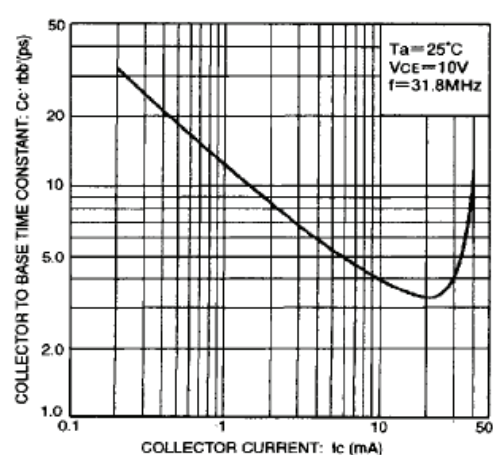


Figure 6

BIPOLAR TRANSISTOR (NPN)

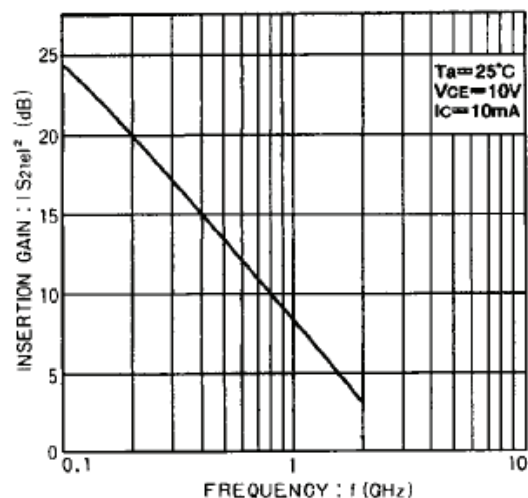


Figure 7

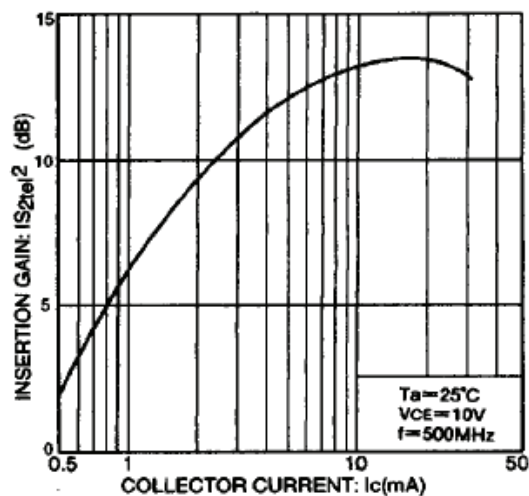


Figure 8

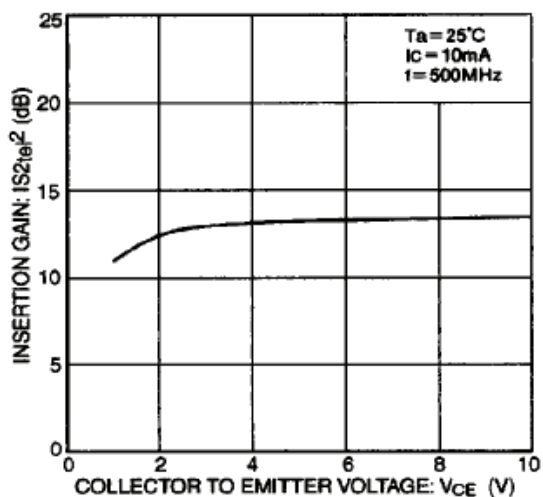


Figure 9

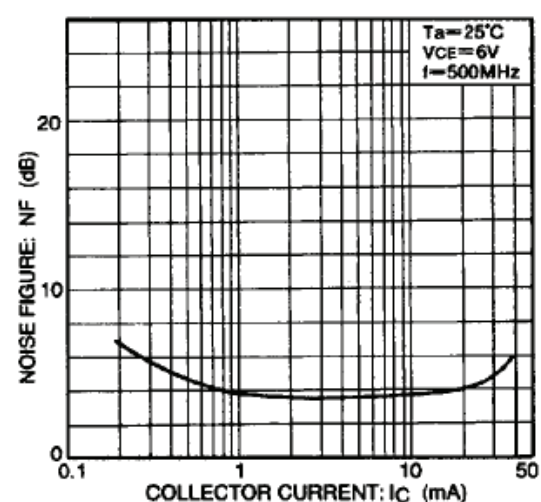


Figure 10

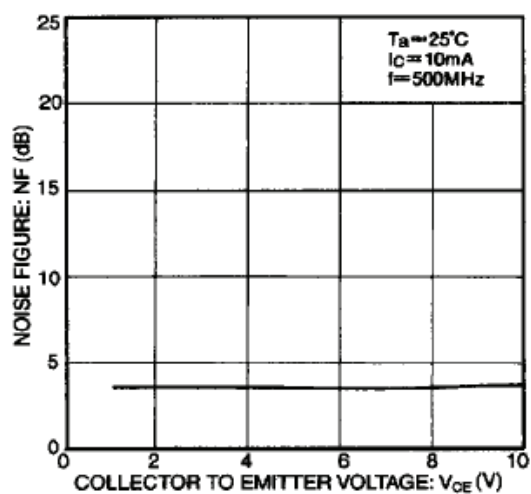
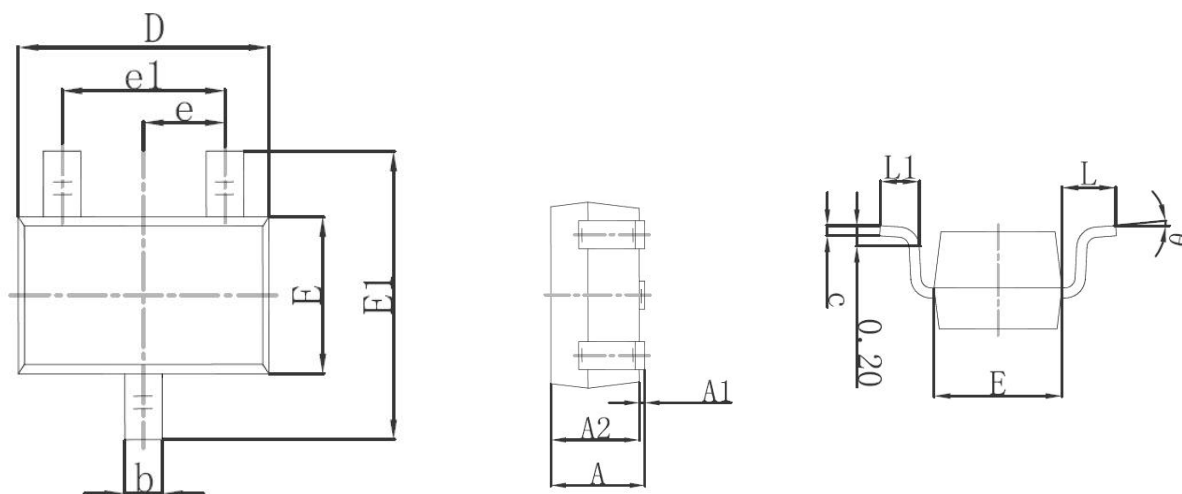
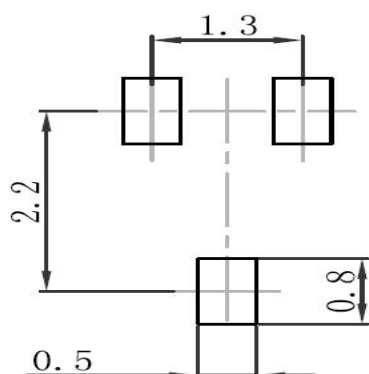


Figure 11

BIPOLAR TRANSISTOR (NPN)
SOT-323 Package Outline Dimensions


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.200	0.400	0.008	0.016
c	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650TYP		0.026TYP	
e1	1.200	1.400	0.047	0.055
L	0.525REF		0.021REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

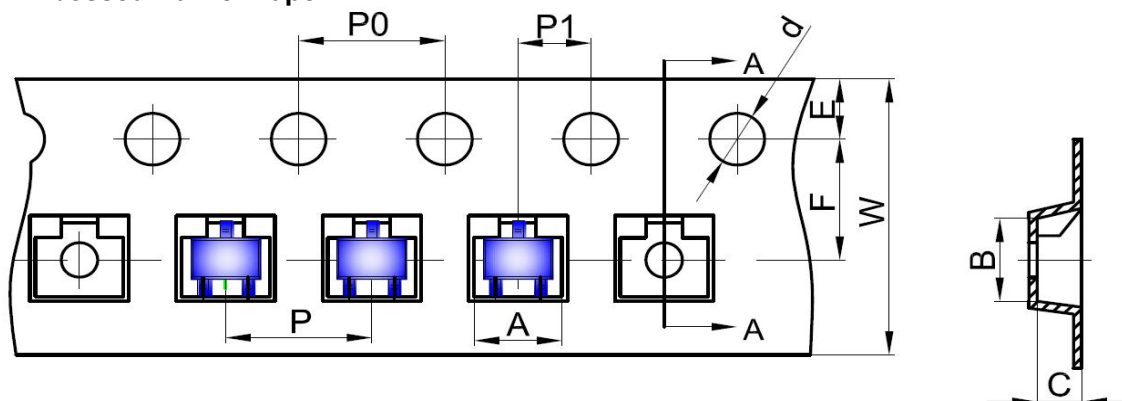
SOT-323 Suggested Pad Layout

Note:

1. Controlling dimension: in millimeters
2. General tolerance: $\pm 0.05\text{mm}$
3. The pad layout is for reference purposes only

BIPOLAR TRANSISTOR (NPN)

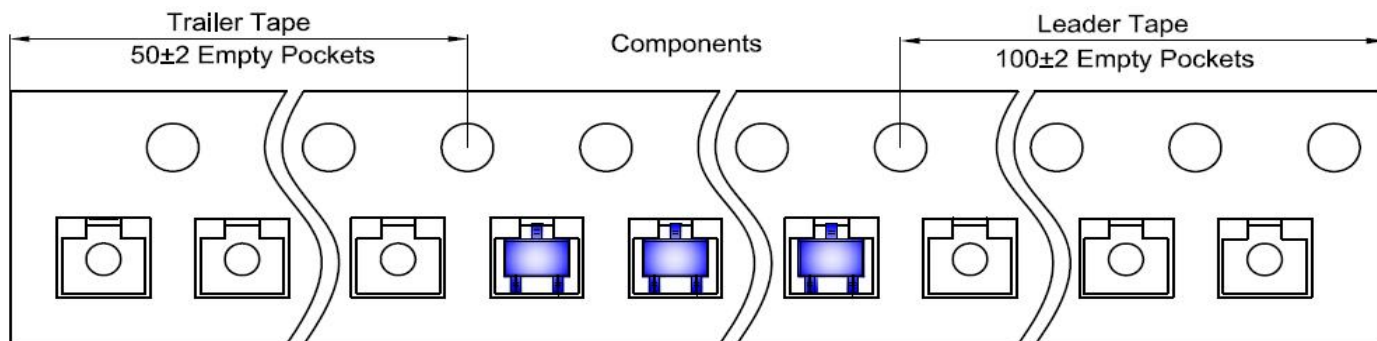
SOT-323 Tape and Reel

SOT-323 Embossed Carrier Tape

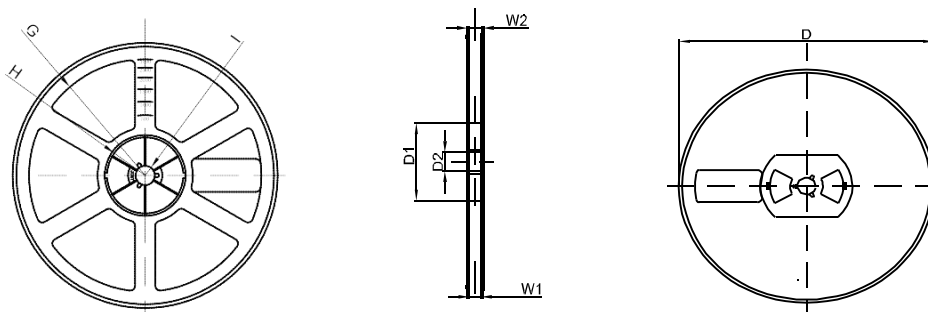


DIMENSIONS ARE IN MILLIMETER										
TYPE	A	B	C	d	E	F	P0	P	P1	W
SOT-323	2.25	2.55	1.19	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00
TOLERANCE	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1

SOT-323 Tape Leader and Trailer



SOT-323 Reel



DIMENSIONS ARE IN MILLIMETER								
REEL OPTION	D	D1	D2	G	H	I	W1	W2
7" DIA	Ø178	54.40	13.00	R78	R25.60	R6.50	9.50	12.30
TOLERANCE	±2	±1	±1	±1	±1	±1	±1	±1